NSN 5961-01-271-1061



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-271-1061 **Inclosure Material:** Metal **Overall Length:** 1.230 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud Features Provided: Hermetically sealed case **Overall Width Across Flats:** 0.677 inches Thready Qty Per Inch (tpi): 28 **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 reverse voltage, peak **Current Rating Per Characteristic:** 600.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 turret Shelf Life: N/a **Unit Of Measure:**

Demilitarization: Yes - demil/mli

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